

/ Descriptions

TO-252

NPN

Silicon NPN transistor in a TO-252 Plastic Package.

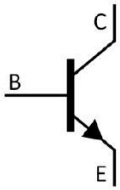
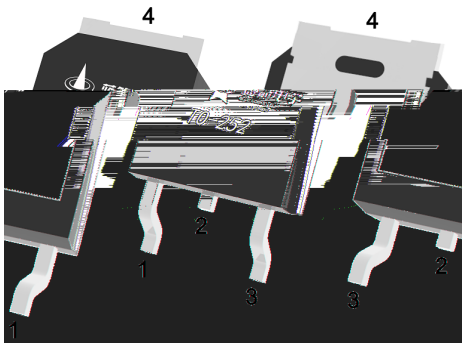
/ Features

AEC-Q101

High collector-Emitter breakdown voltage, Suitable for transformer, Qualified to AEC-Q101 Standards for High Reliability, HF Product.

/ Applications

High voltage general purpose applications, Meet the stringent requirements of automotive applications.

/ Equivalent Circuit**/ Pinning**

PIN1 Base

PIN 2,4 Collector

PIN 3 Emitter

/ h_{FE} Classifications & Marking

See Marking Instructions.

/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	300	V
Collector to Emitter Voltage	V_{CEO}	300	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	500	mA
Collector Power Dissipation	P_C	1.56	W
Collector Power Dissipation	$P_C(T_C=25)$	15	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

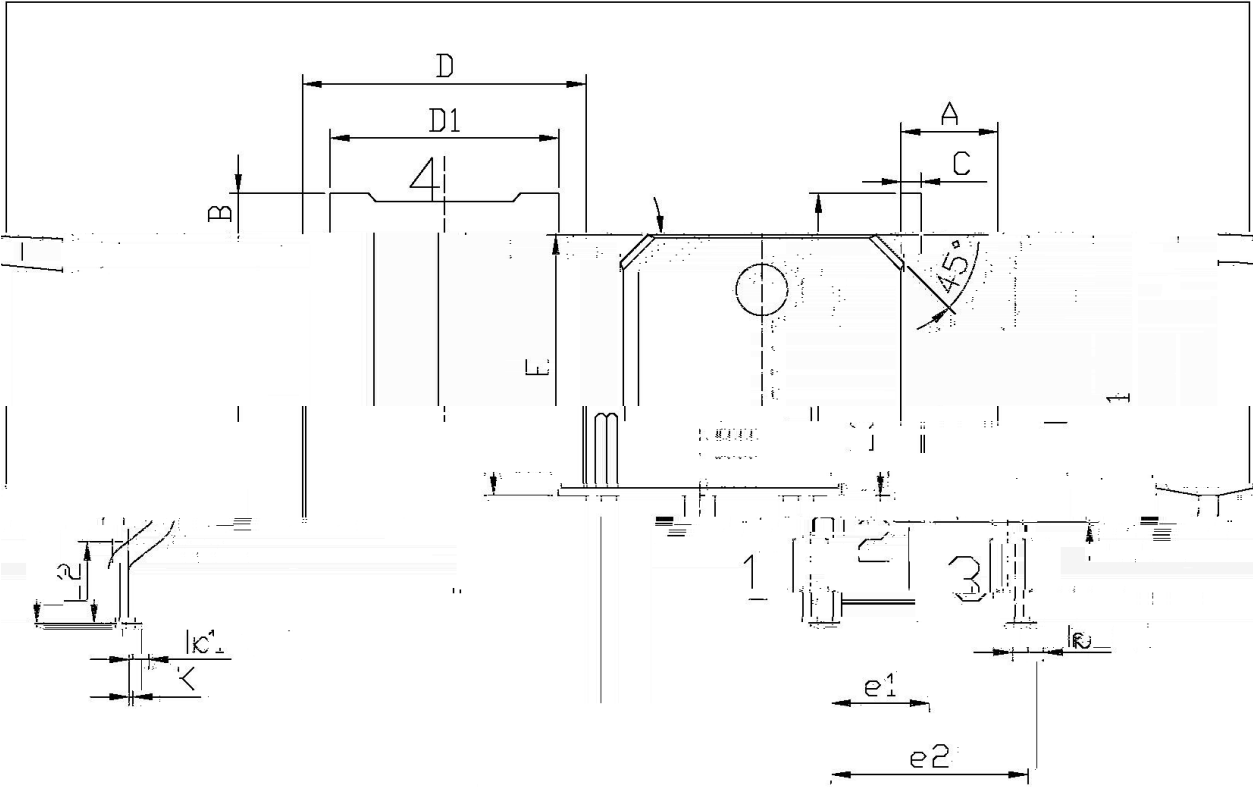
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=0.1mA$ $I_E=0$	300			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=1.0mA$ $I_B=0$	300			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E=0.1mA$ $I_C=0$	5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=300V$ $I_E=0$			100	μA
Emitter Cut-Off Current	I_{EBO}	$V_{CE}=3V$ $I_C=0$			100	μA
DC Current Gain	h_{FE}	$V_{CE}=10V$ $I_C=50mA$	30		240	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=50mA$ $I_B=5.0mA$			1.0	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=50mA$ $I_B=5.0mA$			1.2	V

/ Electrical Characteristic Curve



I Package Dimensions

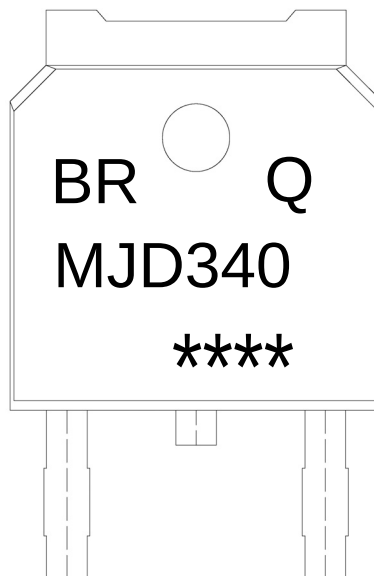


单位: mm

Dimensions In Millimeters		Dimensions In Millimeters	
Symbol	Min	Symbol	Min
A	2.20	E	5.95
B	0.95	e1	2.24
C	0.45	e2	1.10
D	6.45	L2	1.70
D1	5.10	L3	0.60
H	6.75	K	0.00

T0-252

/ Marking Instructions



BR

Q

MJD340

Note:

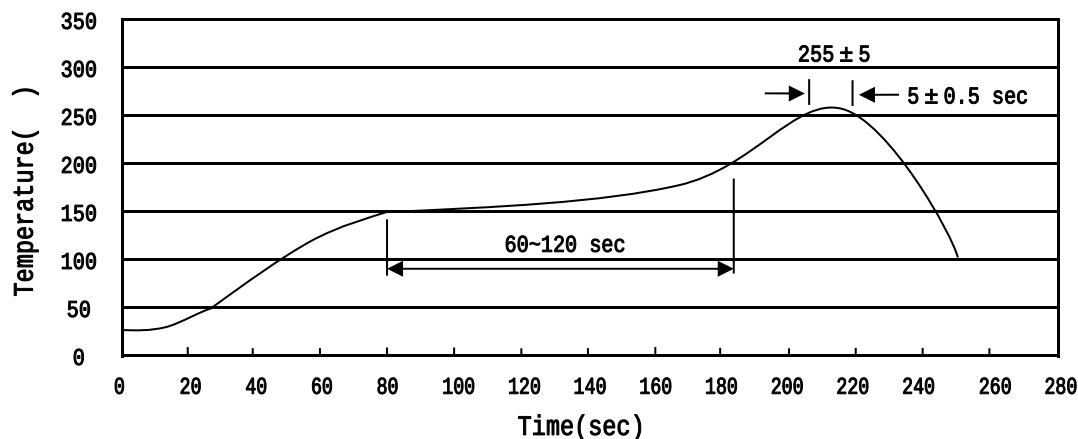
BR: Company Code

Q: Automobile halogen-free product Code

MJD340: Product Type

****: Lot No. Code, code change with Lot No

() / Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- 150 200 60 120sec; 1.Preheating:150~200 , Time:60~120sec.
- 255±5 5±0.5sec; 2.Peak Temp.:255±5 , Duration:5±0.5sec.
- 2 10 /sec. 3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension (unit mm ³)		
	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
TO-252	2,500	2	5,000	6	30,000	13 ×16	360×360×50	380×335×366

/ TUBE

Package Type	Units					Dimension (unit mm ³)		
	Units/Tube	Tubes/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Tube	Inner Box	Outer Box
TO-251/252	75	48	3,600	5	18,000	526×20.5×5.25	555×164×50	575×290×180

/ Notices